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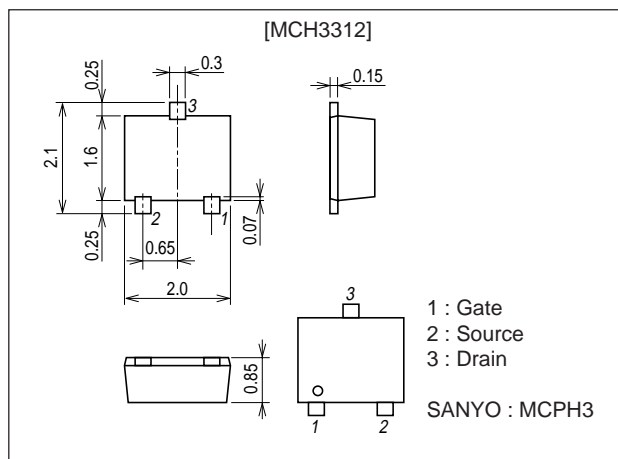
MCH3312 — P-Channel Silicon MOSFET Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit : mm
2167A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-2	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-8	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (900mm ² ×0.8mm)	1	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-1A	1.4	2.0		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-1A, V _{GS} =-10V		110	145	mΩ
	R _{DS(on)2}	I _D =-0.5A, V _{GS} =-4V		205	290	mΩ

Marking : JM

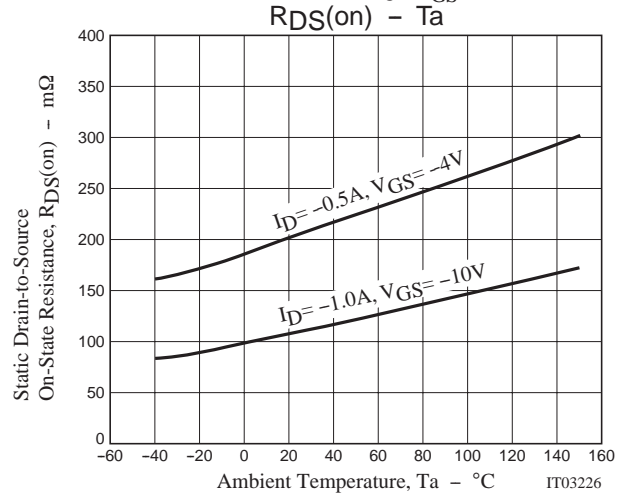
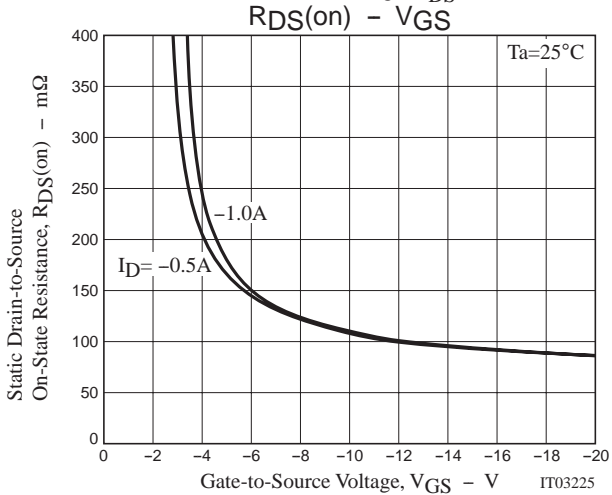
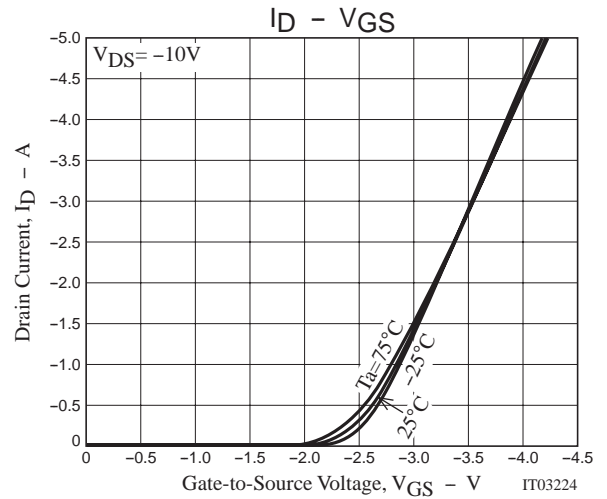
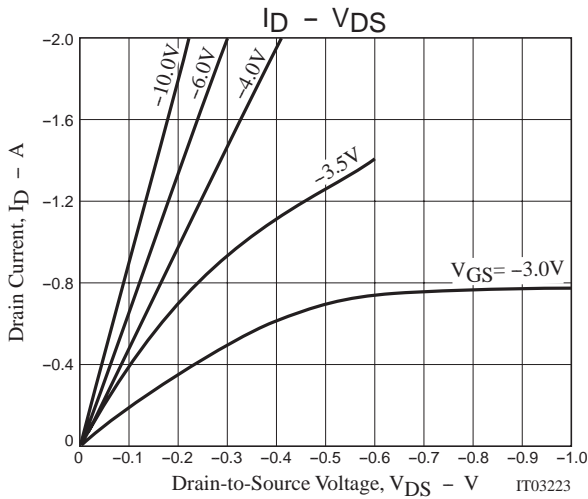
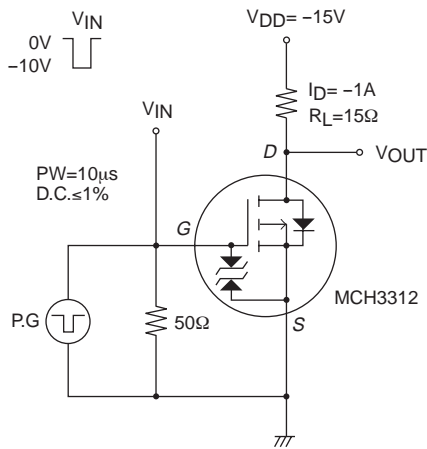
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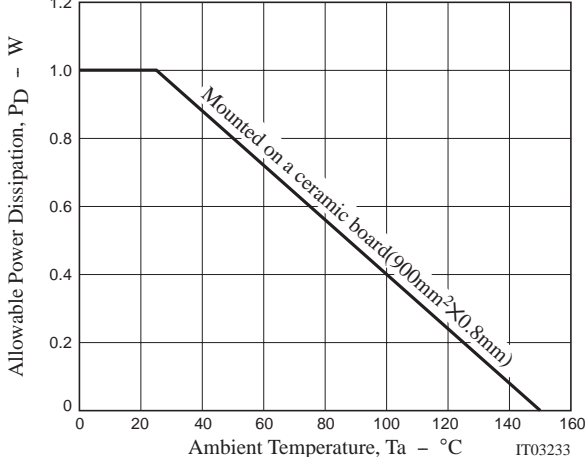
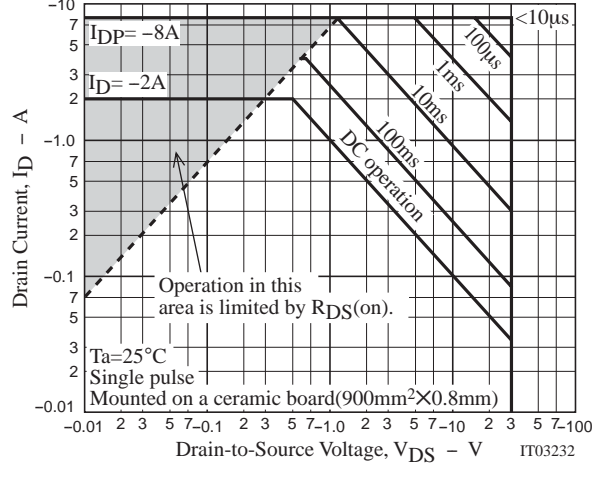
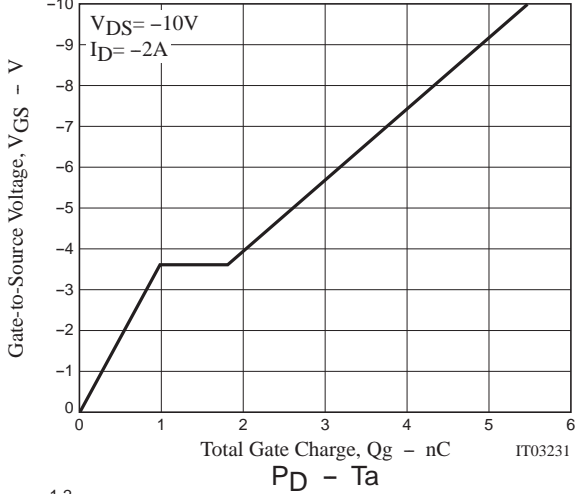
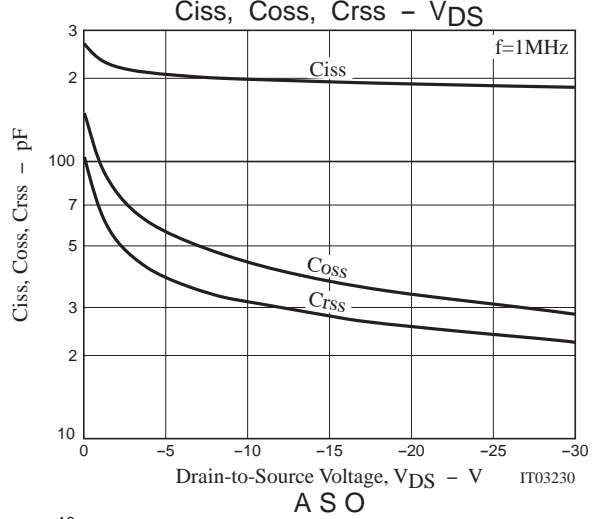
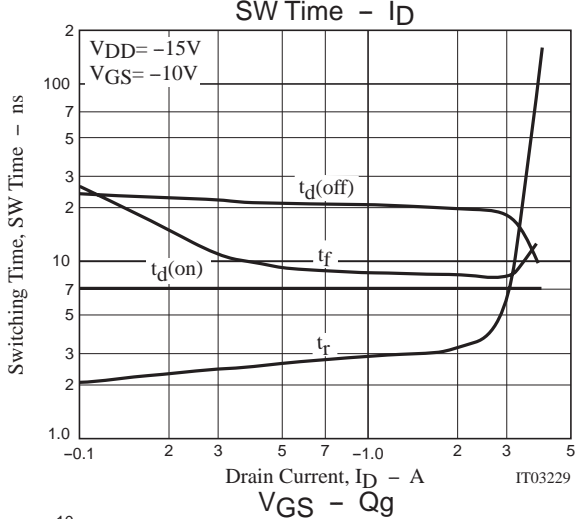
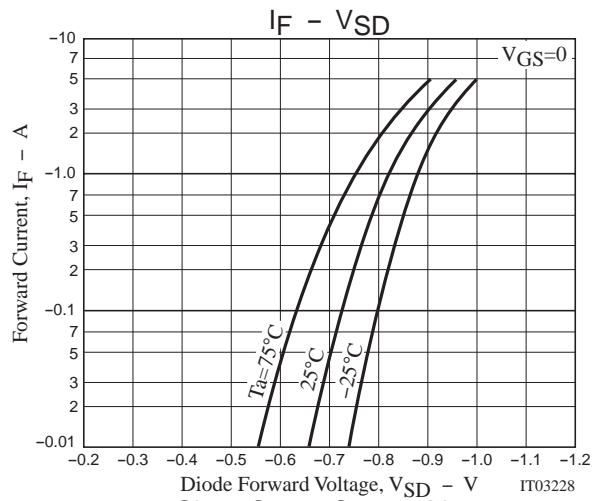
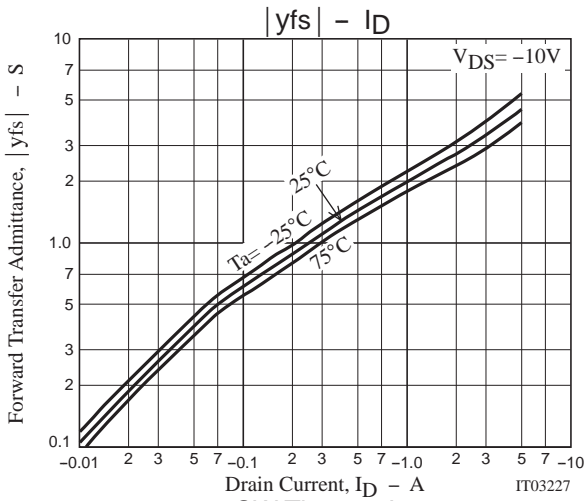
MCH3312

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		200		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		47		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		32		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		7.2		ns
Rise Time	t _r	See specified Test Circuit		2.9		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit		21		ns
Fall Time	t _f	See specified Test Circuit		8.7		ns
Total Gate Charge	Q _g	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		5.5		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		0.98		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =-10V, V _{GS} =-10V, I _D =-2A		0.82		nC
Diode Forward Voltage	V _{SD}	I _S =-2A, V _{GS} =0	-0.85		-1.5	V

Switching Time Test Circuit





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